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Renesas Technology Corp. Customer Support Dept. April 1, 2003



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Silicon NPN Epitaxial, Darlington

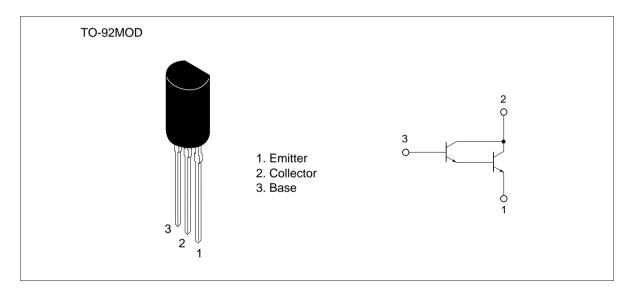


ADE-208-1143 (Z) 1st. Edition Mar. 2001

#### Application

- Low frequency power amplifier
- Complementary pair with 2SA1193(K)

#### Outline



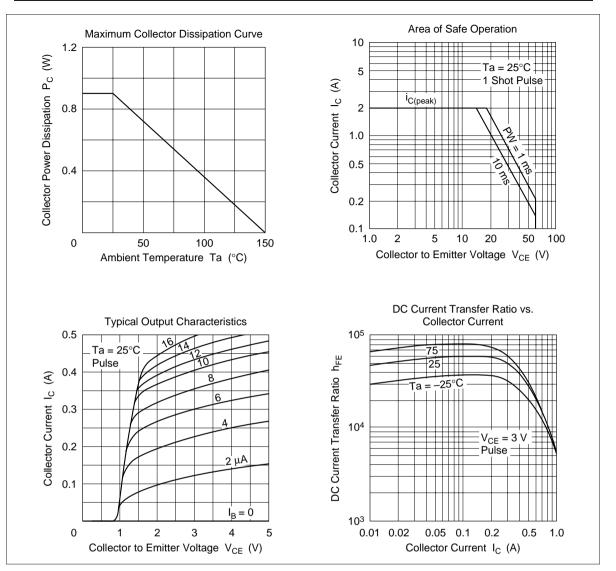
#### **Absolute Maximum Ratings** (Ta = $25^{\circ}$ C)

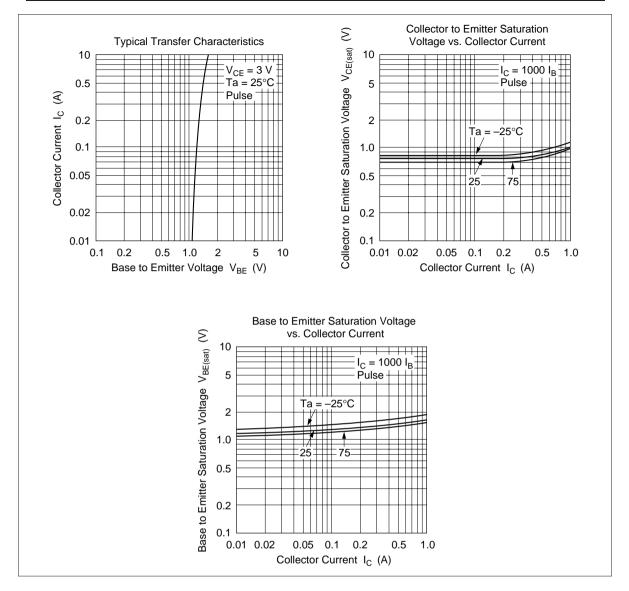
| Item                         | Symbol               | Ratings     | Unit |
|------------------------------|----------------------|-------------|------|
| Collector to base voltage    | V <sub>CBO</sub>     | 60          | V    |
| Collector to emitter voltage | V <sub>CEO</sub>     | 60          | V    |
| Emitter to base voltage      | V <sub>EBO</sub>     | 7           | V    |
| Collector current            | Ι <sub>c</sub>       | 1           | А    |
| Collector peak current       | i <sub>C(peak)</sub> | 2           | А    |
| Collector power dissipation  | Pc                   | 0.9         | W    |
| Junction temperature         | Tj                   | 150         | °C   |
| Storage temperature          | Tstg                 | -55 to +150 | °C   |

#### **Electrical Characteristics** (Ta = 25°C)

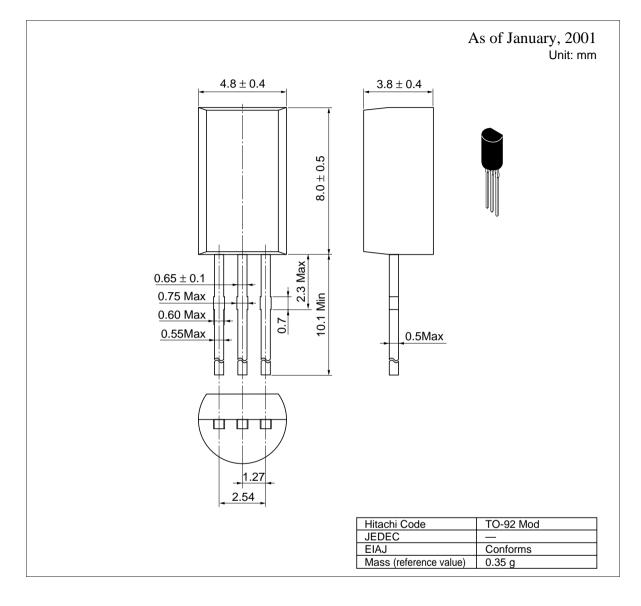
| Item                                    | Symbol               | Min  | Тур | Мах | Unit | Test conditions                                   |
|---|----------------------|------|-----|-----|------|---|
| Collector to base breakdown voltage     | $V_{\rm (BR)CBO}$    | 60   | _   | —   | V    | $I_{c} = 0.1 \text{ mA}, I_{E} = 0$               |
| Collector cutoff current                | I <sub>CEO</sub>     | —    | —   | 100 | μΑ   | $V_{ce}$ = 60 V, $R_{be}$ = $\infty$              |
| Emitter cutoff current                  | I <sub>EBO</sub>     | —    | —   | 100 | μΑ   | $V_{EB} = 7 V, I_{C} = 0$                         |
| DC current transfer ratio               | h <sub>FE</sub>      | 4000 | —   |     |      | $V_{ce} = 3 \text{ V}, I_c = 0.5 \text{ A}^{*1}$  |
| Collector to emitter saturation voltage | $V_{\text{CE(sat)}}$ | _    | _   | 1.5 | V    | $I_c = 500 \text{ mA}, I_B = 0.5 \text{ mA}^{*1}$ |
| Base to emitter saturation voltage      | $V_{\text{BE(sat)}}$ | —    | —   | 2.0 | V    | $I_c = 500 \text{ mA}, I_B = 0.5 \text{ mA}^{*1}$ |
| Notor 1 Dulas test                      |                      |      |     |     |      |   |

Note: 1. Pulse test





#### **Package Dimensions**



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